Femtosecond laser inscribed phase masks for fibre Bragg grating sensor inscription

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ABSTRACT

We present femtosecond laser inscribed phase masks for the inscription of Bragg gratings in optical fibres. The principal advantage is the flexibility afforded by the femtosecond laser inscription, where sub-surface structures define the phase mask period and mask properties. The masks are used to produce fibre Bragg gratings having different orders according to the phase mask period. The work demonstrates the incredible flexibility of femtosecond lasers for the rapid prototyping of complex and reproducible mask structures. We also consider three-beam interference effects, a consequence of the zeroth-order component present in addition to higher-order diffraction components.

Keywords: Phase masks, femtosecond laser, inscription, laser-material interaction, fibre Bragg gratings, Talbot effect

1. INTRODUCTION

The use of phase masks for the production of fibre gratings was spurred by research such as that of Bennion *et al* who first demonstrated side-etched gratings in 1986 [1]. Later work by Hill *et al* [2] provided the necessary impetus for the mass production of fibre Bragg gratings (FBGs). The role of the phase mask is to spatially modulate the UV-writing beam to produce a suitable interference pattern in the fibre core that defines the extent and strength of the Bragg grating. Phase masks are typically surface relief structures, with the gratings most often etched in low loss, fused silica via an electron-beam or holographic process. A key advantage of electron-beam lithography is the writing of complicated patterns, potentially offering quadratic chirps and Moire patterns written directly into the mask's structure. However, lithographically produced phase masks are generated by typically stitching together small subsections (400 μm x 400 μm) of periodic corrugations on the mask substrate to fabricate larger phase structures. An error in the precise positioning of the various subsections results in what is commonly referred to as stitching error [3]. Holographically produced phase masks have no stitch error. The masks act as precision diffraction gratings that upon irradiation by a monochromatic source divide the light evenly between two or more orders. These created orders interfere in the area behind the phase mask where they overlap and this interference pattern is recorded in the fibre to create the FBG. An area that is particularly topical in recent years is the use of femtosecond (fs) lasers to induce refractive index changes or ablation in transparent materials. A focused femtosecond laser pulse can fundamentally change a material's physical properties through strong non-linear absorption of the laser energy, allowing for the fabrication of intricate microstructures on the surface of opaque materials, or within the bulk volume of optically transparent glass or polymeric materials. In this work we present the improvement of phase masks written with the point by point femtosecond inscription [4, 5]. The masks are used to fabricate Bragg gratings in fibres. The fabrication method offers the potential for rapid modification of the mask properties by either manipulating the coding of the sample motion relative to the inscription laser beam and/or by accurately controlling the laser parameters, such as the pulse duration, repetition rate and the laser pulse energy. Our method allows for large area masks without the requirement to stitch together small subsections.

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1.1 Phase mask inscription

A series of diffraction patterns were femtosecond-laser inscribed in the bulk volume of pure fused-silica substrates, approximately 50 μm below the surface. The uniformity of the substrate was found to be critical in the reproducibility of the masks. To ensure that this was the case we chose a glass known to be highly transmissive from a wavelength range of 193 nm to 693 nm, thereby making the masks suitable for the production of FBGs. The fs laser writing setup consisted of an Amplitude Systemes s-Pulse HP, producing sub 500 fs laser pulses at a centre wavelength of 1026 nm, and repetition rate of 100 kHz. The laser energy ranged from 1 μJ to 8 μJ at the laser exit. All inscriptions were conducted using a 100X objective (Mititoyo MPlan Apo NIR Series) with a numerical aperture of 0.5. This was chosen as it provides a long working distance with a high NA thus generating a small and highly accurate focal spot that the structures written required. The accurate nature of the spot through the sample due to the large NA and working distance are critical to the direct write nature of the work. The FWHM of the laser spot size incident on the samples was approximately 1.5 μm. The samples were mounted on an Aerotech motion control system (x-y ABL 1000 air bearing stages) that was controlled with custom coding. The repeatability and precision of these stages allows this work to be carried out with minimal stitch errors and with the nanometre accuracy required to obtain the precise lines written in the fused silica substrates. The samples were secured perpendicular to the incident femtosecond laser beam. Low stress mounting of the samples ensured unwanted effects that could change the uniformity of the written structure.

The best results were achieved for a laser energy at the sample of 350 nJ per pulse, at a translation speed of 2 mm/s. This proved to be a good compromise to produce reliable and clear lines for a reasonable mask inscription time. Fig. 1 (a) offers a close up of the inscription process, with the laser plasma within the bulk volume of the substrate clearly visible. In Fig. 1(b) we observe the series of masks that were inscribed, whereas Fig. 1 (c) shows a transmission microscope image of a typical mask line structure for a period of approximately 2 μm. The actual masks periods were chosen to provide FBG spectra in the 1550 nm transmission window. Hence we selected periods of 1071.18 nm for the mask designated M10, and 2142.36 nm and 3180.00 nm for the masks designated M8 and M12, respectively. The period affected the inscription time, varying from one and a half hours to five hours, accordingly.

(a)   (b)   (c)
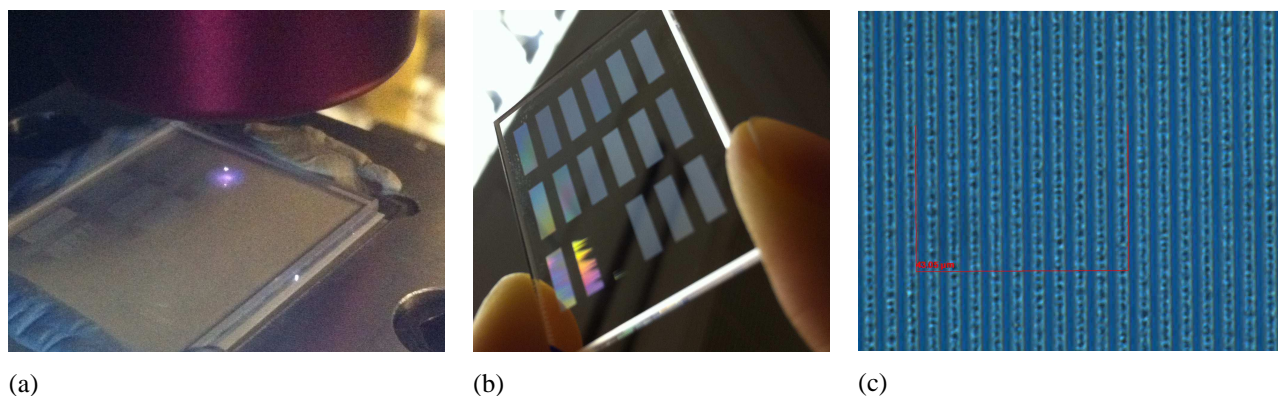
Fig. 1 (a) close up of the inscription process showing the laser plasma within the substrate, (b) a series of inscribed masks, (c) transmission microscope image of a typical mask line structure for a period of approximately 2μm.

The samples were viewed with an optical microscope (Fig. 1 (c)) and an optical profilometer (WYKO 9100NT), Fig. 2. As we are viewing subsurface structures, our interest in using the optical profilometer is to measure the period and view the consistency of the line structure amplitude; hence we use an intensity mode, where absolute values are not measured with regard to amplitude. Fig. 2 (a) shows a typical 3-D plot of the mask, whereas Fig. 2 (b) shows a line section across the mask, from which we observe that the mask has both excellent consistency in amplitude and period.

In Fig. 3 we observe the potential for the fs inscription method, where we observe the actual diffraction performance of the mask, from which we can discern that it is behaving as a phase mask, when the mask is illuminated by a 244 nm UV laser, as typically used for FBG inscription.
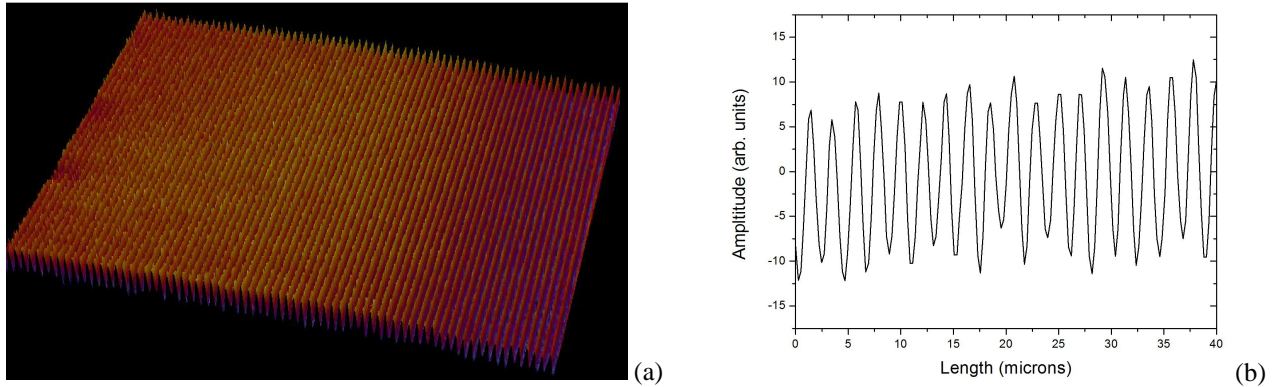
Fig. 2. Typical optical profilometer 3-D plot of the mask, (b) a line section of the mask; we observe that the mask has both excellent consistency in amplitude and period.

Fig. 3. The diffraction performance of a typical femtosecond-laser inscribed mask, when illuminated by a UV laser, as typically used for FBG inscription.

1.2 FBG inscription

A series of FBGs were inscribed in hydrogenated Fibrecore PS-1250/1500, a B/Ge co-doped optical fibre. The fibres were hydrogenated at 200 *bar* and 80°C for 48 hours and stored for a short period at -40°C before FBG inscription. Table 1 summarises the FBGs that were inscribed using the phase masks. The grating transmission spectra were recorded using a broadband light source and optical spectrum analyser. Fig. 4 shows a transmission spectrum for a FBG UV-written using mask M12 and having a 7-*dB* notch depth.
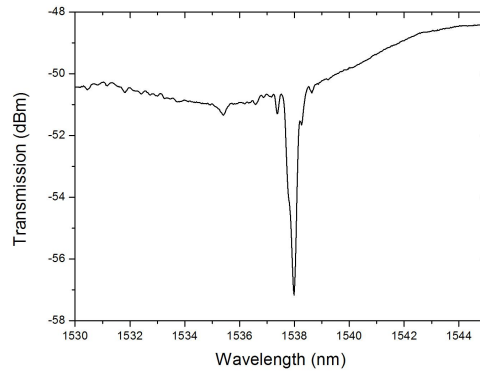

Fig. 4. FBG inscribed using the femtosecond inscribed phase mask.

Table 1. FBG inscription parameters

Grating	Mask ID	Mask Type	UV Laser Power (*W*)	Scans	Speed (*mm/s*)
FBG4	M12	3rd order 1550 *nm*	0.1	1	0.05
FBG5	M10	1st order 1550 *nm*	0.1	3	0.05
FBG7	M8	2nd order 1550 *nm*	0.1	1	0.05

1.3 Zeroth order suppression

With regard to the inscription of the Bragg gratings using the femtosecond inscribed masks, one needs to consider the effect that the zeroth-order has on any interference pattern that is generated by the mask. This is essentially three-beam interference that results between the non-zero suppression of the zeroth-order with the different diffracted order pairs. Higher order contributions are typically ignored as they can be minimized by increasing the spacing between the fiber and the mask. Hence when using the femtosecond inscribed masks for Bragg grating inscription we will tend to inscribe second order Bragg gratings instead of a conventional first order Bragg grating. This is not in itself a major drawback, but pertains from the fact that we have yet to optimise the effective laser induced "etch-depth" of the mask and its relation to the UV wavelength used for the Bragg grating inscription. This is under development and we anticipate far greater diffraction efficiencies once this issue has been resolved.

2. CONCLUSION

We have presented improved femtosecond-laser inscribed sub-surface phase/amplitude masks for the production of FBGs in hydrogenated optical fibre. The work demonstrates the proof of concept and flexibility for the use of femtosecond lasers to make complex and reproducible masks. This approach to fabricating masks enables the patterns to be below the surface which is helpful in the protection of the tooling and reproducibility of gratings due to positioning variations. One does need to account for the effect of the non-zero contribution of the strong zeroth-order component that is present in the transmission characteristics of the mask and that modifies the ideal, anticipated interference pattern typically used for Bragg grating inscription. Hence when using the femtosecond inscribed masks for Bragg grating inscription we are inscribing second order Bragg gratings instead of a conventional first order Bragg grating. This is not in itself a major drawback, but the effective laser induced "etch-depth" of the mask needs to be optimised with respect to the UV wavelength used for the Bragg grating inscription. This is under development and we anticipate far greater diffraction efficiencies once this issue has been resolved.

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